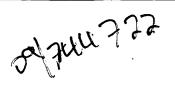
	From the INTERNATIONAL BUREAU			
PCT	То:			
NOTIFICATION OF THE RECORDING	AGFA-GEVAERT	N.V.		
OF A CHANGE	Attn.:Van Ostaey	en, Marc		
(PCT Rule 92bis.1 and	Corporate IP Dep Septestraat 27	artment		
Administrative Instructions, Section 422)	B-2640 Mortsel			
	BELGIQUE			
Date of mailing (day/month/year) 10 July 2000 (10.07.00)				
Applicant's or agent's file reference	IMPORTA	ANT NOTIFICATION		
A-G 6564-PC Jo				
International application No.	International filing date (c 20 July 1999 (20.			
PCT/EP99/05147	20 July 1999 (20.	<u> </u>		
1. The following indications appeared on record concerning:	· · · · · · · · · · · · · · · · · · ·			
X the applicant the inventor	the agent	the common representative		
Name and Address	State of Natio	nality State of Residence)	
AGFA-GEVAERT AG	DE	DE		
Kaiser-Wilhelm-Allee D-51373 Leverkusen	Telephone No	•		
Germany	<u></u>			
	Facsimile No.			
	Teleprinter No) .		
2. The International Bureau hereby notifies the applicant that the	following change has bee	n recorded concerning:		
the person X the name X the add	ess X the nation	lity X the residence		
Name and Address	State of Natio	nality State of Residence	•	
AGFA-GEVAERT NAAMLOZE VENNOOTSCHAP	BE	BE		
Septestraat 27 B-2640 Mortsei	Telephone No	•		
Belgium	Faccimile No.			
	Facsimile No.			
	Teleprinter No).		
3. Further observations, if necessary:				
4. A copy of this notification has been sent to:				
X the receiving Office	the design	ated Offices concerned		
the International Searching Authority	X the elected	Offices concerned		
X the International Preliminary Examining Authority	other:			
	Authorized officer			
The International Bureau of WIPO 34, chemin des Colombettes		Karkachi		
1211 Geneva 20, Switzerland	Α.	NGINGOIII		
Facsimile No.: (41-22) 740.14.35	Telephone No.: (41-22) 338	3.83.38		

	From the INTERNATIONAL BUREAU			
PCT	То:			
NOTIFICATION OF THE RECORDING OF A CHANGE (PCT Rule 92bis.1 and Administrative Instructions, Section 422)	AGFA-GEVAERT N.V. Attn.:Van Ostaeyen, Marc Corporate IP Department Septestraat 27 B-2640 Mortsel			
Date of mailing (day/month/year) 10 July 2000 (10.07.00)	BELGIQUE			
Applicant's or agent's file reference A-G 6564-PC Jo	IMPORTANT NOTIFICATION			
International application No. PCT/EP99/05147	International filing date (day/month/year) 20 July 1999 (20.07.99)			
The following indications appeared on record concerning: the applicant	the agent X the common representative			
Name and Address AGFA-GEVAERT AG Kaiser-Wilhelm-Allee D-51373 Leverkusen Germany	State of Nationality State of Residence Telephone No. 0214 30 71166 Facsimile No.			
	0214 30 534 82 Teleprinter No.			
2. The International Bureau hereby notifies the applicant that the	ne following change has been recorded concerning:			
the person the name X the add				
Name and Address AGFA-GEVAERT N.V. Attn.:Van Ostaeyen, Marc	State of Nationality State of Residence			
Corporate IP Department Septestraat 27 B-2640 Mortsel	Telephone No. Facsimile No.			
Belgium	Teleprinter No.			
3. Further observations, if necessary:				
4. A copy of this notification has been sent to:				
X the receiving Office	the designated Offices concerned			
the International Searching Authority	X the elected Offices concerned			
X the International Preliminary Examining Authority	other:			
The International Bureau of WIPO 34, chemin des Colombettes	Authorized officer A. Karkachi			

1211 Geneva 20, Switzerland

Telephone No.: (41-22) 338.83.38

Facsimile No.: (41-22) 740.14.35



PATENT COOPERATION TREATY



From the INTERNATIONAL BUREAU

PCT

NOTIFICATION OF ELECTION

(PCT Rule 61.2)

Assistant Commissioner for Patents United States Patent and Trademark Office

in its capacity as elected Office

Box PCT

Washington, D.C.20231 **ETATS-UNIS D'AMERIQUE**

Date of	mailing	(day/m	onth	/yea	r)
27	March	2000	127	UЗ	00

27 March 2000 (27.03.00)

Applicant's or agent's file reference

International application No. PCT/EP99/05147

International filing date (day/month/year) 20 July 1999 (20.07.99)

A-G 6564-PC Jo Priority date (day/month/year) 30 July 1998 (30.07.98)

Applicant

CRONE, Klaus-Peter et al

1.	The designated Office is hereby notified of its election made:	
	X in the demand filed with the International Preliminary Examining Authority on:	
	04 February 2000 (04.02.00)	
	in a notice effecting later election filed with the International Bureau on:	
2.	The election X was	
	was not	
	made before the expiration of 19 months from the priority date or, where Rule 32 applies, within the time limit under Rule 32.2(b).	

The International Bureau of WIPO 34, chemin des Colombettes 1211 Geneva 20, Switzerland

Authorized officer

R. E. Stoffel

Facsimile No.: (41-22) 740.14.35 Telephone No.: (41-22) 338.83.38

PATENT COOPERATION TREATY



RDM/IP-LEV Dr. A. Jochum

Eiro.: 2 2. Feb. 2000

P¢T

From the INTERNATIONAL BUREAU

To:

AGFA-GEVAERT AG Kaiser-Wilhelm-Allee D-51373 Leverkusen ALLEMAGNE

NOTICE INFORMING THE APPLICANT OF THE COMMUNICATION OF THE INTERNATIONAL APPLICATION TO THE DESIGNATED OFFICES

(PCT Rule 47.1(c), first sentence)

Date of mailing (day/month/year)

10 February 2000 (10.02.00)

Applicant's or agent's file reference

A-G 6564-PC Jo

PCT/EP99/05147

International filing date (day/month/year) Priorit

20 July 1999 (20.07.99)

IMPORTANT NOTICE

Priority date (day/month/year) 30 July 1998 (30.07.98)

Applicant

AGFA-GEVAERT AG et al

 Notice is hereby given that the International Bureau has communicated, as provided in Article 20, the international application to the following designated Offices on the date indicated above as the date of mailing of this Notice: AU,CN,EP,IL,JP,KP,KR.US

In accordance with Rule 47.1(c), third sentence, those Offices will accept the present Notice as conclusive evidence that the communication of the international application has duly taken place on the date of mailing indicated above and no copy of the international application is required to be furnished by the applicant to the designated Office(s).

2. The following designated Offices have waived the requirement for such a communication at this time:

AE,AL,AM,AP,AT,AZ,BA,BB,BG,BR,BY,CA,CH,CU,CZ,DE,DK,EA,EE,ES,FI,GB,GD,GE,GH,GM,HR,HU,ID,IN,IS,KE,KG,KZ,LC,LK,LR,LS,LT,LU,LV,MD,MG,MK,MN,MW,MX,NO,NZ,OA,PL,PT,RO,RU,SD,SE,SG,SI,SK,SL,TJ,TM,TR,TT,UA,UG,UZ,VN,YU,ZA,ZW

SD,SE,SG,SI,SK,SL,TJ,TM,TR,TT,UA,UG,UZ,VN,YU,ZA,ZW
The communication will be made to those Offices only upon their request. Furthermore, those Offices do not require the applicant to furnish a copy of the international application (Rule 49.1(a-bis)).

 Enclosed with this Notice is a copy of the international application as published by the International Bureau on 10 February 2000 (10.02.00) under No. WO 00/07250

REMINDER REGARDING CHAPTER II (Article 31(2)(a) and Rule 54.2)

If the applicant wishes to postpone entry into the national phase until 30 months (or later in some Offices) from the priority date, a demand for international preliminary examination must be filed with the competent International Preliminary Examining Authority before the expiration of 19 months from the priority date.

It is the applicant's sole responsibility to monitor the 19-month time limit.

Note that only an applicant who is a national or resident of a PCT Contracting State which is bound by Chapter II has the right to file a demand for international preliminary examination.

REMINDER REGARDING ENTRY INTO THE NATIONAL PHASE (Article 22 or 39(1))

If the applicant wishes to proceed with the international application in the national phase, he must, within 20 months or 30 months, or later in some Offices, perform the acts referred to therein before each designated or elected Office.

For further important information on the time limits and acts to be performed for entering the national phase, see the Annex to Form PCT/IB/301 (Notification of Receipt of Record Copy) and Volume II of the PCT Applicant's Guide.

The International Bureau of WIPO 34, chemin des Colombettes 1211 Geneva 20, Switzerland Authorized officer

J. Zahra

Facsimile No. (41-22) 740.14.35

Telephone No. (41-22) 338.83.38

Form PCT/IB/308 (July 1996)

3084970

REQUEST

The undersigned requests that the present international application be processed according to the Patent Cooperation Treaty.

For receiving Of	fice use only
PCT/E International Application No.	P 99/05142
2 0 JUL 1999 International Filing Date	(2 0. 07. 1999)
EUROPEAN PATE PCT INTERNATION Name of receiving Office and "PCT	NAL APPLICATION

Applicant's or agent's file reference (if desired) (12 characters maximum) A-G 6564-PC J٥ Box No. I TITLE OF INVENTION "Method of producing solar cells" APPLICANT Box No. II Name and address: (Family name followed by given name; for a legal entity, full official designation. The address must include postal code and name of country. The country of the address indicated in this Box is the applicant's State (that is, country) of residence if no State of residence is indicated below.) This person is also inventor. Telephone No. 0214 30 71166 Agfa-Gevaert AG Kaiser-Wilhelm-Allee Facsimile No. D 51373 Leverkusen 0214 30 534 82 DE Teleprinter No. 85 101-265byd State (that is, country) of nationality: State (that is, country) of residence: DE This person is applicant for the purposes of: the States indicated in the Supplemental Box all designated States except the United States of America the United States of America only all designated States Box No. III FURTHER APPLICANT(S) AND/OR (FURTHER) INVENTOR(S) Name and address: (Family name followed by given name; for a legal entity, full official designation. The address must include postal code and name of country. The country of the address indicated in this Box is the applicant's State (that is, country) of residence if no State This person is: of residence is indicated below.) applicant only Crone, Klaus-Peter applicant and inventor Im Bungert 4 D 53773 Hennef inventor only (If this check-box is marked, do not fill in below.) DE State (that is, country) of residence: State (that is, country) of nationality: This person is applicant all designated States except the United States of America the United States of America only the States indicated in all designated the Supplemental Box for the purposes of: Further applicants and/or (further) inventors are indicated on a continuation sheet. AGENT OR COMMON REPRESENTATIVE; OR ADDRESS FOR CORRESPONDENCE Box No. IV The person identified below is hereby/has been appointed to act on behalf X | common representative agent of the applicant(s) before the competent International Authorities as: Name and address: (Family name followed by given name; for a legal entity, full official designation. The address must include postal code and name of country.) Telephone No. 0214 30 71166 Aqfa-Gevaert AG Facsimile No. Kaiser-Wilhelm-Allee D 51373 Leverkusen 0214 30 534 82 DE Teleprinter No. 85 101-265-byd Address for correspondence: Mark this check-box where no agent or common representative is/has been appointed and the x space above is used instead to indicate a special address to which correspondence should be sent.

Sheet	No		2	2		
SHEEL	140.	•	•	٠,	٠	

Continuation of Box No. III FURTHER APPLICANT(S) AND/OR (FURTHER) INVENTOR(S)				
If none of the following sub-boxes is used, this sheet should not be i	ncluded in the request.			
Name and address: (Family name followed by given name: for a legal entity, full official designation. The address must include postal code and name of country. The country of the address indicated in this Box is the applicant's State (that is, country) of residence if no State of residence is indicated below.) Löffelmann, Günter Am Domberg 9 D 51515 Kürten DE This person is: applicant only X applicant and inventor				
State (that is, country) of nationality: DE State (that is, country) DE	of residence:			
	the United States of America only the States indicated in the Supplemental Box			
Name and address: (Family name followed by given name: for a legal entiry, full official designation. The address must include postal code and name of country. The country of the address indicated in this Box is the applicant's State (that is, country) of residence if no State of residence is indicated below.) Modemann, Karl Heinrich-Heine-Str. 39 D 53225 Bonn DE	This person is: applicant only substitute applicant and inventor inventor only (If this check-box is marked, do not fill in below.)			
State (that is, country) of nationality: DE State (that is, country)) of residence:			
This person is applicant	the United States of America only the States indicated in the Supplemental Box			
Name and address: (Family name followed by given name: for a legal entity, full official designation. The address must include postal code and name of country. The country of the address indicated in this Box is the applicant's State (that is, country) of residence if no State of residence is indicated below.) Koch, Eberhard Königsberger Str. 34 D 51399 Burscheid DE	This person is: applicant only applicant and inventor inventor only (If this check-box is marked, do not fill in below.)			
State (that is, country) of nationality: DE State (that is, country) DE	y) of residence:			
This person is applicant all designated all designated States except for the purposes of:	the United States of America only the States indicated in the Supplemental Box			
Name and address: (Family name followed by given name; for a legal entity, full official designation. The address must include postal code and name of country. The country of the address indicated in this Box is the applicant's State (that is, country) of residence if no State of residence is indicated below.) Saverteig, Wolfgang Walter-Flex-Str. 1 D 51373 Leverkusen DE	This person is: applicant only applicant and inventor inventor only (If this check-box is marked, do not fill in below.)			
State (that is, country) of nationality: DE This person is applicant all designated States except all designated States except	the United States the States indicated in			
for the purposes of: States the United States of America LX	of America only the Supplemental Box			
Further applicants and/or (further) inventors are indicated on another continuation	n sheet.			

Form PCT/RO/101 (continuation sheet) (July 1998)

See Notes to the request form

DESIGNATION OF STATES Box No.V The following designations are hereby made under Rule 4.9(a) (mark the applicable check-boxes; at least one must be marked): Regional Patent AP ARIPO Patent: GH Ghana, GM Gambia, KE Kenya, LS Lesotho, MW Malawi, SD Sudan, SZ Swaziland, UG Uganda, 図 ZW Zimbabwe, and any other State which is a Contracting State of the Harare Protocol and of the PCT Eurasian Patent: AM Armenia, AZ Azerbaijan, BY Belarus, KG Kyrgyzstan, KZ Kazakhstan, MD Republic of Moldova, RU Russian Federation, TJ Tajikistan, TM Turkmenistan, and any other State which is a Contracting State of the Eurasian Patent Convention and of the PCT European Patent: AT Austria, BE Belgium, CH and LI Switzerland and Liechtenstein, CY Cyprus, DE Germany, K DK Denmark, ES Spain, FI Finland, FR France, GB United Kingdom, GR Greece, IE Ireland, IT Italy, LU Luxembourg, MC Monaco, NL Netherlands, PT Portugal, SE Sweden, and any other State which is a Contracting State of the European Patent Convention and of the PCT OA OAPI Patent: BF Burkina Faso, BJ Benin, CF Central African Republic, CG Congo, CI Côte d'Ivoire, CM Cameroon, GA Gabon, GN Guinea, ML Mali, MR Mauritania, NE Niger, SN Senegal, TD Chad, TG Togo, and any other State M which is a member State of OAPI and a Contracting State of the PCT (if other kind of protection or treatment desired, specify C.Jobed on dotted line) & GW Guinea Bissica Rallp National Patent (if other kind of protection or treatment desired, specify on dotted line): LS Lesotho AL Albania X LT Lithuania AM Armenia Austria 図 LU Luxembourg 図 LV Latvia 凩 X ΑÜ 冈 MD Republic of Moldova Azerbaijan X AZ. MG Madagascar Bosnia and Herzegovina BA MK The former Yugoslav Republic of Macedonia ... 区 \mathbf{BB} Barbados BG Bulgaria X 図 MN Mongolia BR Brazil X MW Malawi \boxtimes BY MX Mexico Canada K NO Norway CH and LI Switzerland and Liechtenstein X New Zealand CN China \mathbf{x} Poland CU Cuba Portugal PT Czech Republic CZ RO Romania Ø Russian Federation \mathbf{z} RU DK Denmark..... X Sudan Estonia Ø SD Ø EE Spain SE Sweden X ES \boxtimes SG Singapore Ø FI Slovenia Ø SI 図 GB United Kingdom Slovakia Ø SK Georgia Ø GE 凶 Sierra Leone SL GH Ghana.... \boxtimes Tajikistan TJ X GM Gambia Turkmenistan X TM C- \mathbf{X} GW Guinea-Bisseur Turkey TR Ø HR Croatia Trinidad and Tobago 図 TT Hungary X HU Ukraine X UA B ID Indonesia Uganda X UG $oldsymbol{\mathbb{Z}}$ IL Israel United States of America \mathbf{Z} $oldsymbol{\boxtimes}$ IS Japan \boxtimes JP Uzbekistan UZ Z Kenya KE VN Viet Nam X KG Kyrgyzstan YU Yugoslavia Democratic People's Republic of Korea ZW Zimbabwe Check-boxes reserved for designating States (for the purposes of a national patent) which have become party to the PCT after issuance of this sheet: GO IN AE ZA TORREST AND ALL THE COUNTRIES WHICH have KR Republic of Korea adoled 囡 Rolep $oldsymbol{\mathbb{Z}}$ Saint Lucia PCT-by (asseded to the and X LK Sri Lanka Filing date of this application Ø LR Liberia

Precautionary Designation Statement: In addition to the designations made above, the applicant also makes under Rule 4.9(b) all other designations which would be permitted under the PCT except any designation(s) indicated in the Supplemental Box as being excluded from the scope of this statement. The applicant declares that those additional designations are subject to confirmation and that any designation which is not confirmed before the expiration of 15 months from the priority date is to be regarded as withdrawn by the applicant at the expiration of that time limit. (Confirmation of a designation consists of the filing of a notice specifying that designation and the payment of the designation and confirmation fees. Confirmation must reach the receiving Office within the 15-month time limit.)

Supplemental Box

If the Supplemental Box is not used, this sheet should not be included in the request.

- 1. If, in any of the Boxes, the space is insufficient to furnish all the information. in such case, write "Continuation of Box No. ..." [indicate the number of the Box] and furnish the information in the same manner as required according to the captions of the Box in which the space was insufficient, in particular:
- (i) if more than two persons are involved as applicants and/or inventors and no "continuation sheet" is available: in such case, write "Continuation of Box No. III" and indicate for each additional person the same type of information as required in Box No. III. The country of the address indicated in this Box is the applicant's State (that is, country) of residence if no State of residence is indicated below;
- (ii) if, in Box No. II or in any of the sub-boxes of Box No. III, the indication "the States indicated in the Supplemental Box" is checked: in such case, write "Continuation of Box No. III" or "Continuation of Boxes No. II and No. III" (as the case may be), indicate the name of the applicant(s) involved and, next to (each) such name, the State(s) (and/or, where applicable, ARIPO, Eurosian, European or OAPI patent) for the purposes of which the named person is applicant;
- (iii) if, in Box No. II or in any of the sub-boxes of Box No. III, the inventor or the inventor/applicant is not inventor for the purposes of all designated States or for the purposes of the United States of America: in such case, write "Continuation of Box No. II" or "Continuation of Box No. III" or "Continuation of Boxes No. II and No. III" (as the case may be), indicate the name of the inventor(s) and, next to (each) such name, the State(s) (and/or, where applicable, ARIPO, Eurosian, European or OAPI patent) for the purposes of which the named person is inventor;
- (iv) if, in addition to the agent(s) indicated in Box No. IV, there are further agents: in such case, write "Continuation of Box No. IV" and indicate for each further agent the same type of information as required in Box No. IV:
- (v) if, in Box No. V, the name of any State (or OAPI) is accompanied by the indication "patent of addition." or "certificate of addition," or if, in Box No. V, the name of the United States of America is accompanied by an indication "continuation" or "continuation-in-part": in such case, write "Continuation of Box No. V" and the name of each State involved (or OAPI), and after the name of each such State (or OAPI), the number of the parent title or parent application and the date of grant of the parent title or filing of the parent application:
- (vi) If, in Box No. VI, there are more than three earlier applications whose priority is claimed: in such case, write "Continuation of Box No. VI" and indicate for each additional earlier application the same type of information as required in Box No. VI;
- (vii) if, in Box No. VI, the earlier application is an ARIPO application: in such case, write "Continuation of Box No. VI", specify the number of the item corresponding to that earlier application and indicate at least one country party to the Paris Convention for the Protection of Industrial Property for which that earlier application was filed.
- 2. If, with regard to the precautionary designation statement contained in Box No. V, the applicant wishes to exclude any State(s) from the scope of that statement: in such case, write "Designation(s) excluded from precautionary designation statement" and indicate the name or two-letter code of each State so excluded.
- 3. If the applicant claims, in respect of any designated Office, the benefits of provisions of the national law concerning non-prejudicial disclosures or exceptions to lack of novelty: in such case, write "Statement concerning non-prejudicial disclosures or exceptions to lack of novelty" and furnish that statement below.

Continuation of Box No. IX

A-G 6564-PC		Sì	neet No				
Box No. VI PRIORITY CI	AIM		[Further prior	rity claims are indicated	in the Supplemental Box.	
Filing date		ımber			Where earlier applicati		
of earlier application (day/month/year)	of earlier	application	N .	application: ountry	regional application:* regional Office	international application: receiving Office	
tem (1)			1		Ì		
(30.7.98)	400 5			DE			
30 Juli 1998	198	14 358 2		<u>UE</u>			
tem (2)			}				
			<u> </u>		 		
item (3)							
The receiving Office is requested to prepare and transmit to the International Bureau a certified copy of the earlier application(s) (only if the earlier application was filed with the Office which for the purposes of the present international application is the receiving Office) identified above as item(s):							
* Where the earlier application I: Convention for the Protection of	s an ARIPO e Industrial Pri	application, it is operty for which	mandatory t that earlier	o indicate in the application was	Supplemental Box at least filed (Rule 4.10(b)(ii)). Se	one country party to the Paris e Supplemental Box.	
		RCHING AU			arliar search: referenc	e to that search (if an earlier	
Choice of International Sear- (if two or more International Sear- competent to carry out the inter- the Authority chosen; the two-le	earching Au motional seat	thorities are se	equest to t earch has be eate (day/mo	m carried out by	or requested from the Inte Number	crnational Searching Authority): Country (or regional Office)	
ISA /							
Box No. VIII CHECK LIS	ST; LANG	UAGE OF FI	LING			1 - 41 - 1	
This international application the following number of she	ets:	This internation			anled by the item(s) ma	rked below:	
request :	5			wer of attorne	y		
description (excluding sequence listing part) :	4				y; reference number, if	any:	
claims :	1	. —		ing lack of sign			
abstract :	1	5. 🔀 priorit	y documen	(s) identified in	n Box No. VI as itcm(s):		
drawings :	_	6. 🔲 transla	tion of inte	mational appli	cation into (language):		
sequence listing part	*	7. Separate indications concerning deposited microorganism or other biological material					
of description :				amino acid ser	mence listing in comput	er readable form	
Total number of sheets:	11	9. 🗷 other	(specify): [ebit or	der, Demand 1 - copies	or publication	
Figure of the drawings wh should accompany the abstr	ich act:		Language internation	of filing of the al application:	COPIES		
D N. TY CICNATUR	DE OF APP	LICANT OR	AGENT				
Next to each signature, indicate the	he name of the	person signing an	d the capacity	in which the pers	on signs (if such capacity is n	of obvious from reading the request).	
				for	further sign	atures	
AGFA-GEVA	ERLAG	•		വില	se see sunnl	emental	
1 /2/	. / ~			shee	t 4 (will fo	TIOM).	
Jellino!	r. C						
,	l						
Date of actual receipt of international application	of the purpor			g Office use or UL 1999	2 0. 07. 99)	2. Drawings:	
3. Corrected date of actua		•		received:			
the purported internation 4. Date of timely receipt corrections under PCT	onal applica	tion;				not received:	
5 International Searching	Authority			6. Tran	smittal of search copy de search fee is paid.	elayed	
(if two or more are con	npetent):	<u> </u>					
		For	r Internatio	nal Bureau usc	only		
Date of receipt of the receipt of the International Bure	ord copy						
	au:	220				See Notes to the request for	

Form PCT/RO/101 (last sheet) (July 1998)

From the INTERNATIONAL PRELIMINARY EXAMINING AUTHORITY

To:

AGFA-GEVAERT N.V. Attn.:Van Ostaeyen, Marc Corporate IP Department Septestraat 27 B-2640 Mortsel BELGIQUE

PCT

NOTIFICATION OF TRANSMITTAL OF THE INTERNATIONAL PRELIMINARY EXAMINATION REPORT (PCT Rule 71.1)

Date of mailing (day/month/year)

03.10.2000

Applicant's or agent's file reference

A-G 6564-PC Jo

PCT/EP99/05147

International application No.

International filing date (day/month/year)

20/07/1999

IMPORTANT NOTIFICATION

Priority date (day/month/year)

30/07/1998

Applicant

AGFA-GEVAERT NAAMLOZE VENNOOTSCHAP et al.

- 1. The applicant is hereby notified that this International Preliminary Examining Authority transmits herewith the international preliminary examination report and its annexes, if any, established on the international application.
- 2. A copy of the report and its annexes, if any, is being transmitted to the International Bureau for communication to all the elected Offices.
- 3. Where required by any of the elected Offices, the International Bureau will prepare an English translation of the report (but not of any annexes) and will transmit such translation to those Offices.

4. REMINDER

The applicant must enter the national phase before each elected Office by performing certain acts (filing translations and paying national fees) within 30 months from the priority date (or later in some Offices) (Article 39(1)) (see also the reminder sent by the International Bureau with Form PCT/IB/301).

Where a translation of the international application must be furnished to an elected Office, that translation must contain a translation of any annexes to the international preliminary examination report. It is the applicant's responsibility to prepare and furnish such translation directly to each elected Office concerned.

For further details on the applicable time limits and requirements of the elected Offices, see Volume II of the PCT Applicant's Guide.

Name and mailing address of the IPEA/

European Patent Office - P.B. 5818 Patentlaan 2 NL-2280 HV Rijswijk - Pays Bas

Tel. +31 70 340 - 2040 Tx: 31 651 epo nl Fax: +31 70 340 - 3016 Sinanovic, E

Authorized officer

Tel.+31 70 340-2672



PATENT COOPERATION TREATY

PCT

INTERNATIONAL PRELIMINARY EXAMINATION REPORT

(PCT Article 36 and Rule 70)

• •	_	ent's file reference	FOR FURTHER ACTION	See Notification of Transmittal of International Preliminary Examination Report (Form PCT/IPEA/416)
A-G 6564-PC Jo				
International application No.			International filing date (day/monti	
PCT/EP9	9/05	147	20/07/1999	30/07/1998
H01L31/1		ent Classification (IPC) or na	tional classification and IPC	
Applicant AGFA-GI	EVAE	ERT NAAMLOZE VEN	NOOTSCHAP et al.	
1. This is	nterna trans	ational preliminary exami smitted to the applicant a	nation report has been prepare ccording to Article 36.	d by this International Preliminary Examining Authority
2. This F	REPC	ORT consists of a total of	6 sheets, including this cover s	sheet.
b	een a	mended and are the bas		ne description, claims and/or drawings which have containing rectifications made before this Authority ions under the PCT).
These	ann	exes consist of a total of	sheets.	
3. This r	eport	contains indications rela	ting to the following items:	
I	\boxtimes	Basis of the report		
II		Priority		
Ш		Non-establishment of c	pinion with regard to novelty, in	ventive step and industrial applicability
IV		Lack of unity of invention	on .	
٧	×	Reasoned statement u citations and explanation	nder Article 35(2) with regard to ons suporting such statement	novelty, inventive step or industrial applicability;
VI		Certain documents cite	ed	•
VII	\boxtimes	Certain defects in the in	nternational application	
VIII	⊠	Certain observations of	n the international application	
Date of sub	missi	on of the demand	Date of	f completion of this report
04/02/20	00		03.10.2	2000
	exam Eur	g address of the international ining authority: opean Patent Office - P.B. 5	818 Patentlaan 2	ized officer
<i><u> </u></i>		2280 HV Rijswijk - Pays Ba: +31 70 340 - 2040 Tx: 31 6		tin, A
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INTERNATIONAL PRELIMINARY **EXAMINATION REPORT**

International application No. PCT/EP99/05147

 Basis of the rep 	port
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١.	Bas	is of the report								
1.	This report has been drawn on the basis of (substitute sheets which have been furnished to the receiving Office response to an invitation under Article 14 are referred to in this report as "originally filed" and are not annexed to the report since they do not contain amendments.):									
	Des	Description, pages:								
	1-4		as originally	filed						
	Clai	ims, No.:								
	1-6		as originally	filed						
2.	The	amendments have	resulted in th	ne cancel	llation of:					
		the description,	pages:							
		the claims,	Nos.:							
		the drawings,	sheets:							
3.					ome of) the amendments had not been made, since they have been as filed (Rule 70.2(c)):					
4.	Add	litional observations	s, if necessary	y:						
V.	Rea app	asoned statement of the	under Article s and explan	e 35(2) w ations si	rith regard to novelty, inventive step or industrial upporting such statement					
1.	Stat	tement								
	Nov	velty (N)	Yes: No:	Claims Claims	1-3,5 4,6					
	Inve	entive step (IS)	Yes: No:	Claims Claims	1-3 4-6					
	Indi	ustrial applicability ((IA) Yes: No:	Claims Claims	1-6					

INTERNATIONAL PRELIMINARY EXAMINATION REPORT

International application No. PCT/EP99/05147

2. Citations and explanations

see separate sheet

VII. Certain defects in the international application

The following defects in the form or contents of the international application have been noted:

see separate sheet

VIII. Certain observations on the international application

The following observations on the clarity of the claims, description, and drawings or on the question whether the claims are fully supported by the description, are made:

see separate sheet

Re Item V

Reasoned statement under Article 35(2) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement

1.) In this report reference is made to the following documents, cited in the International Search Report:

D1: Patent Abstracts of Japan, Vol. 11, Nr. 286 (E-541), 16 September 1987, & JP-A-62084568

D2: Patent Abstracts of Japan, Vol. 10, Nr. 376 (E-464), 13 December 1986, & JP-A-61168271

D3: Patent Abstracts of Japan, Vol. 17, Nr. 434 (E-1412), 11 August 1993, & JP-A-5090624

The following document D4 was not cited in the International Search Report.

D4: Solar Energy Materials and Solar Cells, Vol. 43 (1996), pages 93-98

2.) The subject-matter of claim 1 meet the requirements of Art. 33(2)(3) PCT, as it is considered as new and inventive with respect to the cited state of the art. Indeed both documents D1 and D2 disclose a method of forming a solar cell by depositing a photovoltaically active layer on a support of a polymeric organic material having a glass transition temperature of from 90°C to 200°C (see D1, abstract and figure and D2, abstract). In D2 the deposition is carried out at a substrate temperature below the glass transition temperature of the polymer.

No cited document describes a step of annealing the deposited film for a period of 0.01 to 1 s at temperatures of at least 250°C, by means of a laser having an energy from 2 to 5000 W/mm², so that it is considered that claim 1 is new and inventive.

- 3.) Also the combination of the subject-matter of claim 1 with the additional features of the dependent claims 2 and 3 is considered as new and inventive (Art. 33(2)(3) PCT.
- 4.) The subject-matter of independent claim 4 does not meet the requirements of Art.

INTERNATIONAL PRELIMINARY International application No. PCT/EP99/05147 EXAMINATION REPORT - SEPARATE SHEET

33(2)(3) PCT, because it lacks novelty.

Indeed both documents D1 and D2 disclose a solar cell comprising one photovoltaically active layer on a support of a polymeric organic material having a glass transition temperature of from 90°C to 200°C (see D1, abstract and figure and D2, abstract). Therefore all features of claim 1 are known from D1 or D2 and consequently claim 4 is not novel.

5.) The subject-matter of claim 6, dependent on claim 4, is also known from D1 (see D1, abstract and figure).

Consequently this claim cannot add anything new to the subject-matter of claim 4, on which it depends (Art. 33(2)(3) PCT).

The subject-matter of claim 5, dependent on claim 4, is known from D3 (see D3, abstract and figure).

Consequently this claim cannot add anything inventive to the subject-matter of claim 4, on which it depends (Art. 33(3) PCT).

6.) All claims 1-6 meet the requirements of industrial applicability of Art. 33(4) PCT.

Re Item VII

Certain defects in the international application

Contrary to the requirements of Rule 5.1(a)(ii) PCT, the relevant background art disclosed in the documents D1, D2 and D3 are not mentioned in the description, nor are these documents identified therein.

Re Item VIII

Certain observations on the international application

- 1.) The subject-matter of claim 1 of the application does not satisfy the requirements of Art. 6 PCT.
- 1.1) Indeed in claim 1 a method of coating a polymeric material with a photovoltaic active layer is disclosed, without any specifications as to the kind of deposited material. In the description only thin semiconductor layers are disclosed. For the man skilled in the photovoltaic technology thin film materials are a class of materials with well defined properties (polycrystalline, microcrystalline or amorphous structure and a thickness of

INTERNATIONAL PRELIMINARY International application No. PCT/EP99/05147 EXAMINATION REPORT - SEPARATE SHEET

some microns), different from the thicker layers of monocrystalline devices. Following the description, page 1, lines 1-3 and the example given at page 4 the method of the invention relates only to the production of thin film semiconductor layers. Therefore, in order for the claim to be fully supported by the description (Art. 6 PCT; PCT Preliminary Examination Guidelines, Section IV, III-6.1; PCT Gazette S-07/1998, 29 October 1998) only thin film of photovoltaically active materials should be claimed.

1.2) Moreover it appears that the claimed method could not be directly used for all kind of thin film materials known to the skilled man at the filing date of the application. Indeed considering the semiconductor material CulnSe₂ and related compounds (containing also the elements Ga, Al or S in the molecule) it seems that it is not possible to obtain a thin film of such material using the method of claim 1. Such a thin film deposition requires normally a selenization at high temperature and for a longer time. Referring to the teaching of document D4, a selenization at 400°C for one hour is required to form a thin film layer with the required stoichiometry (see D4, pages 93-95). For this reason a polyimide sheet was used as substrate material. Following the PCT Guidelines, Section IV, III-6.1-III-6.4 (PCT Gazette S-07/1998, 29 October 1998) generalizations are only admitted if supported by the description and if there is no reason to suppose that the invention cannot be worked through the whole of the field claimed.

PATENT COOPERATION TREATY

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INTERNATIONAL PRELIMINARY EXAMINATION REPORT

(PCT Article 36 and Rule 70)

Appl	licant's c	r age	nt's file reference		See Notific	ation of Transmittal of International
A-G	6564	-PC	Jo	FOR FURTHER AC	TION Preliminar	/ Examination Report (Form PCT/IPEA/416)
Inter	national	appli	cation No.	International filing date (d	lay/month/year)	Priority date (day/month/year)
PC	T/EP99	9/05	147	20/07/1999		30/07/1998
			nt Classification (IPC) or na	tional classification and IPC	;	
H01	1L31/1	8				
Appl	licant					
AG	FA-GE	VAE	RT NAAMLOZE VEN	NOOTSCHAP et al.		
1.	This in	terna	ational preliminary exam	ination report has been	prepared by this Inte	ernational Preliminary Examining Authority
''	and is	trans	smitted to the applicant a	according to Article 36.		
2.	This R	EPO	RT consists of a total of	6 sheets, including this	cover sheet.	
				d b ANNEVEC i a cha	ata of the description	n claims and/or drawings which have
	be	en a	mended and are the bas	sis for this report and/or	sheets containing re	n, claims and/or drawings which have actifications made before this Authority
	(s	ee R	ule 70.16 and Section 60	07 of the Administrative	Instructions under t	ne PCT).
	These	anne	exes consist of a total of	sheets.		
ŀ						
3.	This re	port	contains indications rela	ating to the following iten	ns:	
:	ı	\boxtimes	Basis of the report			
	11		Priority			
l	Ш		Non-establishment of o	pinion with regard to no	velty, inventive step	and industrial applicability
	IV		•			
	V	×	Reasoned statement u	nder Article 35(2) with re ons suporting such state	egard to novelty, inv ement	entive step or industrial applicability;
	VI		Certain documents cite			
1	VII	\boxtimes	Certain defects in the in	nternational application		
	VIII	×	Certain observations of	n the international applic	cation	
Date	e of subr	nissio	on of the demand		Date of completion o	f this report
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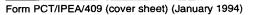
preliminary examining authority: European Patent Office - P.B. 5818 Patentlaan 2 NL-2280 HV Rijswijk - Pays Bas

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Visentin, A

Telephone No. +31 70 340 2530



INTERNATIONAL PRELIMINARY EXAMINATION REPORT

International application No. PCT/EP99/05147

I.	Basi	is of the report			Office in
1.	roen	report has been dra conse to an invitation report since they do	n under Artici	le 14 are re	ubstitute sheets which have been furnished to the receiving Office in referred to in this report as "originally filed" and are not annexed to ents.):
	Des	cription, pages:			
	1-4	á	as originally	filed	
	Clai	ms, No.:			
	1-6	•	as originally	filed	
			المحانية المحانية	no concollo	lation of:
2.	The	amendments have	resulted in ti	ie cancena	alion of.
		the description,	pages:		
		the claims,	Nos.:		
		the drawings,	sheets:		
3	. 🗆	This report has bee considered to go b	en establishe eyond the di	ed as if (so sclosure a	ome of) the amendments had not been made, since they have been as filed (Rule 70.2(c)):
4	. Add	ditional observations	s, if necessa	ry:	
\	/. Re ap	asoned statement plicability; citation	under Artic s and expla	le 35(2) wi nations sı	vith regard to novelty, inventive step or industrial supporting such statement
1	. Sta	atement			
	No	ovelty (N)	Yes: No:	Claims Claims	
	Inv	ventive step (IS)	Yes: No:	Claims Claims	
	Inc	dustrial applicability	(IA) Yes: No:	Claims Claims	

INTERNATIONAL PRELIMINARY EXAMINATION REPORT

International application No. PCT/EP99/05147

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see separate sheet

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see separate sheet

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INTERNATIONAL PRELIMINARY **EXAMINATION REPORT - SEPARATE SHEET**

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INTERNATIONAL PRELIMINARY

International application No. PCT/EP99/05147

EXAMINATION REPORT - SEPARATE SHEET

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International application No. PCT/EP99/05147

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WORLD INTELLECTUAL PROPERTY ORGANIZATION International Bureau



INTERNATIONAL APPLICATION PUBLISHED UNDER THE PATENT COOPERATION TREATY (PCT)

51) International Patent Classification 7: H01L 31/18, 31/0392	A1	(11) International Publication Number: WO 00/07250 (43) International Publication Date: 10 February 2000 (10.02.00)
(22) International Application Number: PCT/EP (22) International Filing Date: 20 July 1999 ((30) Priority Data: 198 34 358.2 30 July 1998 (30.07.98) (71) Applicant (for all designated States excee AGFA-GEVAERT AG [DE/DE]; Kaiser-Wilhed D-51373 Leverkusen (DE). (72) Inventors; and (75) Inventors/Applicants (for US only): CRONE, K [DE/DE]; Im Bungert 4, D-53773 Henn LÖFFELMANN, Günter [DE/DE]; Am Dode D-51515 Kürten (DE). MODEMANN, Karl Heinrich-Heine-Strasse 39, D-53225 Bonn (DE Eberhard [DE/DE]; Königsberger Strasse 34, Burscheid (DE). SAUERTEIG, Wolfgang Walter-Flex-Strasse 1, D-51373 Leverkusen (DI (74) Common Representative: AGFA-GEVAER Kaiser-Wilhelm-Allee, D-51373 Leverkusen (DI	20.07.9 Inpt United States of the Control of the C	BR, BY, CA, CH, CN, CU, CZ, DE, DK, EE, ES, FI, GE GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KC KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MD, MG, MK MN, MW, MX, NO, NZ, PL, PT, RO, RU, SD, SE, SG, S SK, SL, TJ, TM, TR, TT, UA, UG, US, UZ, VN, YU, ZA ZW, ARIPO patent (GH, GM, KE, LS, MW, SD, SL, SZ UG, ZW), Eurasian patent (AM, AZ, BY, KG, KZ, ME RU, TJ, TM), European patent (AT, BE, CH, CY, DE, DK ES, FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE), OAF patent (BF, BJ, CF, CG, CI, CM, GA, GN, GW, ML, MF NE, SN, TD, TG). Published With international search report.

(57) Abstract

Organic polymeric films may serve as supporting materials for at least one photovoltaically active layer, if the supporting material consists of a polymeric material with a glass transition temperature of from 90 °C to 200 °C. The coating of the photovoltaically active layer is carried out at temperatures below the glass transition temperature and annealing is carried out at temperatures of at least 250° by means of a laser.

Intern. .al Application No PCT/EP 99/05147

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	JOURNAL OF CRYSTAL GROWTH, NE, NORTH	14.00.00.00	
	PUBLISHING CO. AMSTERDAM, vol. 152, no. 3, page 150-157 XP000	0626678	
	1 TSSN: 0022-0240		
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X	PATENT ABSTRACTS OF JAPAN vol. 011, no. 286 (E-541),	•	
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-	urther documents are listed in the continuation of box C.	X Patent family members are lis	sted in annex.
اشا	urther documents are used in the		international filling date
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cor E* earli	ment defining the general states and a state of the state of particular relevance (international states) and one of particular relevance (international states).	document of particular relevance; cannot be considered novel or ca	innot be considered to
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Į.	NL = 2280 RV 1387/A Tel. (+31-70) 340-2040, Tx. 31 651 epo nl, Fax: (+31-70) 340-3016		

Interna al Application No
PCT/EP 99/05147

	·	PCT/EP 99/05147
Continue	tion) DOCUMENTS CONSIDERED TO BE RELEVANT	
Category °	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
X .	PATENT ABSTRACTS OF JAPAN vol. 010, no. 376 (E-464), 13 December 1986 (1986-12-13) & JP 61 168271 A (SUMITOMO BAKELITE CO LTD;OTHERS: 01), 29 July 1986 (1986-07-29) abstract	4
A	PATENT ABSTRACTS OF JAPAN vol. 008, no. 036 (E-227), 16 February 1984 (1984-02-16) & JP 58 194377 A (KOGYO GIJUTSUIN; OTHERS: 0J), 12 November 1983 (1983-11-12) abstract	1-4,6
A	PATENT ABSTRACTS OF JAPAN vol. 017, no. 434 (E-1412), 11 August 1993 (1993-08-11) & JP 05 090624 A (NISSHA PRINTING CO LTD), 9 April 1993 (1993-04-09) abstract	1,3-6
Α	US 5 304 499 A (BONNET DIETER ET AL) 19 April 1994 (1994-04-19) cited in the application	
A	NISHIWAKI H ET AL: "DEVELOPMENT OF AN ULTRALIGHT, FLEXIBLE A-SI SOLAR CELL SUBMODULE", SOLAR ENERGY MATERIALS AND SOLAR CELLS,NL,ELSEVIER SCIENCE PUBLISHERS, AMSTERDAM, VOL. 37, NR. 3/04, PAGE(S) 295-306 XP000521870 ISSN: 0927-0248 cited in the application	

harormation on patent family members

Interns at Application No
PCT/EP 99/05147

Patent document	Publication date	Patent family member(s)	Publication date
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JP 61168271 A	29-07-1986	NONE	
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WORLD INTELLECTUAL PROPERTY ORGANIZATION International Bureau



INTERNATIONAL APPLICATION PUBLISHED UNDER THE PATENT COOPERATION TREATY (PCT)

(51) International Patent Classification 7:		(11) International Publication Number:	WO 00/07250
H01L 31/18, 31/0392	A1	(43) International Publication Date:	10 February 2000 (10.02.00)
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(21) International Application Number:	PCT/EP99/05147
(22) International Filing Date:	20 July 1999 (20.07.99)

(71) Applicant (for all designated States except US):
AGFA-GEVAERT AG [DE/DE]; Kaiser-Wilhelm-Allee,
D-51373 Leverkusen (DE).

30 July 1998 (30.07.98)

(72) Inventors; and
(75) Inventors/Applicants (for US only): CRONE, Klaus-Peter [DE/DE]; Im Bungert 4, D-53773 Hennef (DE). LÖFFELMANN, Günter [DE/DE]; Am Domberg 9, D-51515 Kürten (DE). MODEMANN, Karl [DE/DE]; Heinrich-Heine-Strasse 39, D-53225 Bonn (DE). KOCH, Eberhard [DE/DE]; Königsberger Strasse 34, D-51399 Burscheid (DE). SAUERTEIG, Wolfgang [DE/DE]; Walter-Flex-Strasse 1, D-51373 Leverkusen (DE).

(74) Common Representative: AGFA-GEVAERT AG; Kaiser-Wilhelm-Allee, D-51373 Leverkusen (DE).

(81) Designated States: AE, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BY, CA, CH, CN, CU, CZ, DE, DK, EE, ES, FI, GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MD, MG, MK, MN, MW, MX, NO, NZ, PL, PT, RO, RU, SD, SE, SG, SI, SK, SL, TJ, TM, TR, TT, UA, UG, US, UZ, VN, YU, ZA, ZW, ARIPO patent (GH, GM, KE, LS, MW, SD, SL, SZ, UG, ZW), Eurasian patent (AM, AZ, BY, KG, KZ, MD, RU, TJ, TM), European patent (AT, BE, CH, CY, DE, DK, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE), OAPI patent (BF, BJ, CF, CG, CI, CM, GA, GN, GW, ML, MR, NE, SN, TD, TG).

Published

With international search report.

(54) Title: METHOD OF PRODUCING SOLAR CELLS

(57) Abstract

(30) Priority Data:

198 34 358.2

Organic polymeric films may serve as supporting materials for at least one photovoltaically active layer, if the supporting material consists of a polymeric material with a glass transition temperature of from 90 °C to 200 °C. The coating of the photovoltaically active layer is carried out at temperatures below the glass transition temperature and annealing is carried out at temperatures of at least 250° by means of a laser.

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Method of producing solar cells

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The invention relates to an economically improved method of producing thin-layer solar cells, e.g. CdTe solar cells (CdTe = cadmium telluride). CdTe is used below merely as an example for all thin-layer solar cells.

CdTe and CdTe/CdS solar cells may be produced by various methods (US-5 304 499), common to all of which is heat treatment at at least 575°C, to achieve adequate efficiency. These temperatures allow the use only of expensive types of glass as supports. The use of glass as a support has the disadvantage that glass panels may be coated with CdTe only in discontinuous manner, irrespective of the coating method selected.

US-5 304 499 describes a method in which coating is carried out at temperatures of only 480 to 520°C, it thus being possible to use cheap types of glass ("window glass").

To this end, it is necessary for the glass firstly to be provided with a transparent, electrically conductive layer, e.g. of doped tin oxide. This is followed by a thin cadmium sulfide layer (CdS), to which the light-sensitive CdTe layer is then applied by sublimation at 480 to 520°C.

The apparatus required for application of the CdTe layer is complex and expensive: support material and CdTe source are held in such a way by opposing graphite blocks, which are heated to the necessary temperature, that the CdTe source is located only 2 to 3 mm from the support surface. Sublimation is then effected in a 0.1 mbar inert gas atmosphere, e.g. a nitrogen, helium, argon or hydrogen atmosphere. Large areas of CdTe-coated material for producing solar cells cannot be produced economically in this way.

30 H. Nishiwaki et al, Solar Energy Materials and Solar Cells 37 (1995) 295 to 306 use a polyimide film as support because this material has sufficient heat resistance in

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comparison to polyethylene terephthalate (PET) and polyethylene naphthalate (PEN), because of its glass transition temperature of more than 500°C. Polyimide has the disadvantage to be insoluble in usual solvents and to be unable to be molten. It is therefore extremely difficult to be processed.

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The known methods do not permit the use of easily produceable films of polymeric organic materials as supports.

The object of the invention was the economic production of a support with a photovoltaically active layer, e.g. a CdTe layer.

A method was surprisingly found, which permits the use of flexible polymeric films for coating with CdTe and annealing, without the polymeric supporting material being damaged by the high temperatures. In this way, a starting material is obtained for high efficiency solar cells.

The invention therefore provides a method of coating organic polymeric supporting materials with CdTe and annealing the CdTe layer of the materials thus coated, characterised in that the supporting material consists of a polymeric material with a glass transition temperature of from 90°C to 200°C and coating of the CdTe layer is carried out at temperatures below the glass transition temperature and annealing at temperatures of at least 250°C, in particular 400 to 600°C, by means of a laser for 0.01 to 1 s with an energy of 2 to 5000 watt per mm².

25 Preferably the supporting material is at least 60 μ m, in particular 90 to 120 μ m, thick and the CdTe layer is at most 30 μ m, in particular 2 to 7 μ m, thick.

Coating is carried out for example with an aqueous or solvent-containing CdTe suspension.

The material is then dried. Suitable coating methods are, for example, flooding and knife coating.

Annealing may be carried out several times; cooling phases are preferably provided between pairs of annealing steps.

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Suitable polymers are PET and PEN. Prior to coating, the polymeric supporting material may be provided with a substrate layer, e.g. of indium-tin oxide, which improves the adhesion of the CdTe layer. The substrate layer should be transparent and electrically conductive.

Suitable lasers are, for example, argon lasers and yag lasers with frequency duplication.

Organic polymeric supporting materials are flexible and thus permit continuous coating using a suitable coating method.

It is especially advantageous for the CdTe particles to be particularly fine, in particular in the form of so-called nano-particles, i.e. particles whose average diameter lies in the nanometric range and amounts, for example, to from 3 to 5 nm.

In this case, it is expedient for an agent to be present during production of the nanoparticles which prevents agglomeration of the nanoparticles, e.g. tributyl-phosphane.

The invention also provides a solar cell comprising at least one CdTe layer at most 30 µm thick on a support, characterised in that the support is a polymeric organic material at least 60 µm thick and having a glass transition temperature of at least 90°C.

Owing to its flexibility, the polymeric organic support permits continuous coating by means of a coater, for example a meniscus or curtain coater, as known from the coating of photographic films.

Example

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A film of PEN 100 μ m thick and 100 cm wide is coated continuously with a suspension containing a dispersant and 31 g of cadmium telluride per litre. The coated film is then dried and the layer applied exhibits a dry layer thickness of 5 μ m.

The film is annealed as follows:

The entire surface is irradiated with an Ar ion laser (wavelength 514 nm; power 7 W) with a focal point of 50 μm. The temperature is adjusted at from 400 to 450°C.

After annealing, the film exhibits light-dependent electrical resistance and is thus suitable for the production of a photovoltaic cell.

The supporting material is not damaged by exposure to the laser.

Claims

1. A method of coating organic polymeric supporting materials with at least one photovoltaically active layer and annealing the materials thus coated, characterised in that the supporting material consists of a polymeric material with a glass transition temperature of from 90°Cto 200°C. Coating is carried out at temperatures below the glass transition temperature and annealing at temperatures of at least 250°, in particular 400 to 600°C, by means of a laser for 0.01 to 1 s with an energy to 2 to 5000 watt per mm².

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- A method according to claim 1, wherein the supporting material is at least 60 μm thick and the photovoltaic layer is at most 30 μm thick.
- 3. A method according to claim 1, wherein the supporting material is of polyethylene terephthalate or polyethylene naphthalate.
 - 4. A solar cell comprising at least one photovoltaically active layer on a support, characterised in that the support is a polymeric organic material having a glass transition temperature of from 90°C to 200°C.

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- 5. A solar cell, according to claim 4, characterised in that the photovoltaically active layer comprises cadmium telluride.
- 6. A solar cell according to claim 4, characterised in that the support consists of polyethylene terephthalate or polyethylene naphthalate.



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INTERNATIONAL SEARCH REPORT

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